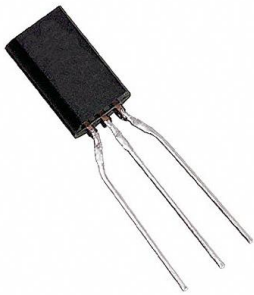


2SC13840S Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	2SC13840S-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	2SC13840S
Description	TRANS NPN 50V 1A TO92L-A1
Detailed Description	Bipolar (BJT) Transistor NPN 50 V 1 A 200MHz 1 W Through Hole TO-92L-A1



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

2SC13840S

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

50 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

1 W

Operating Temperature:

150°C (TJ)

Package / Case:

TO-226-3, TO-92-3 Long Body

Base Product Number:

2SC138

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

1 A

Vce Saturation (Max) @ Ib, Ic:

400mV @ 50mA, 500mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

170 @ 500mA, 10V

Frequency - Transition:

200MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-92L-A1

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.29.0075

ECCN:

EAR99

2SC1384

Silicon NPN epitaxial planar type

For low-frequency power amplification and driver amplification

Complementary to 2SA0684

■ Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- Complementary pair with 2SA0684

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	60	V
Collector-emitter voltage (Base open)	V_{CEO}	50	V
Emitter-base voltage (Collector open)	V_{EBO}	5	V
Collector current	I_C	1	A
Peak collector current	I_{CP}	1.5	A
Collector power dissipation	P_C	1	W
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

■ Package

- Code
TO-92L-A1
- Pin Name
 1. Emitter
 2. Collector
 3. Base

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

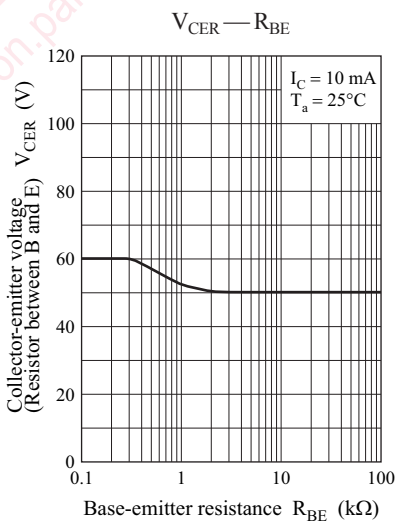
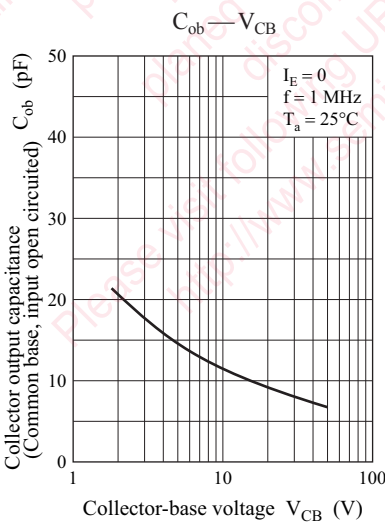
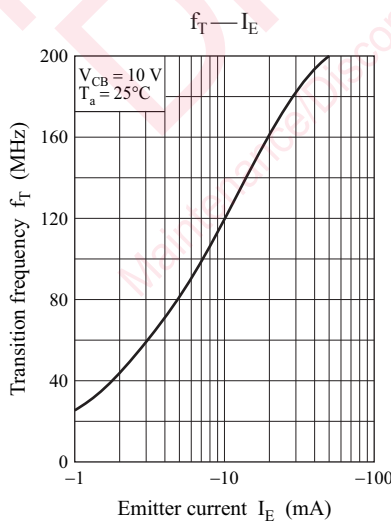
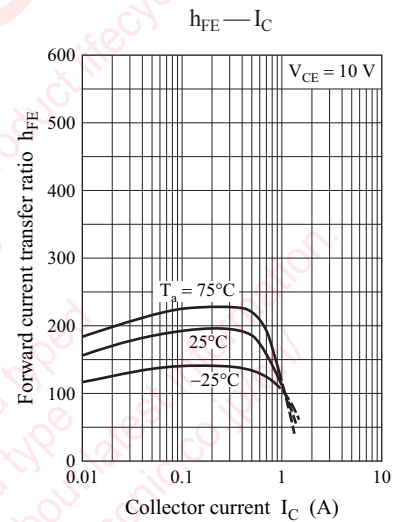
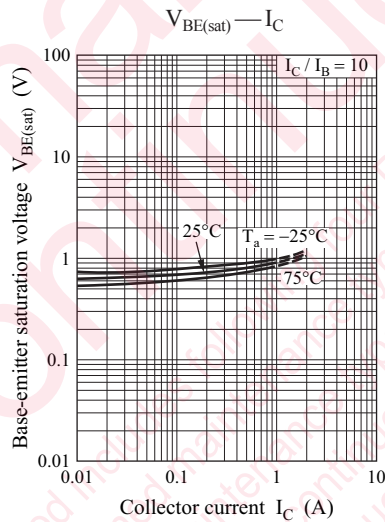
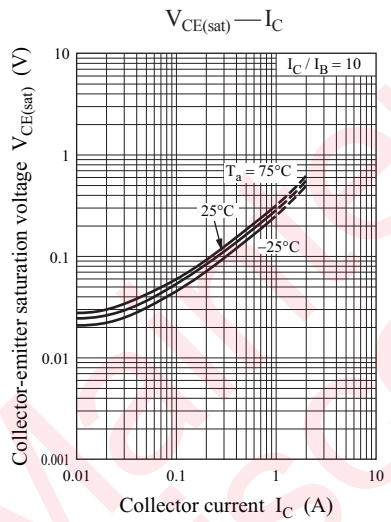
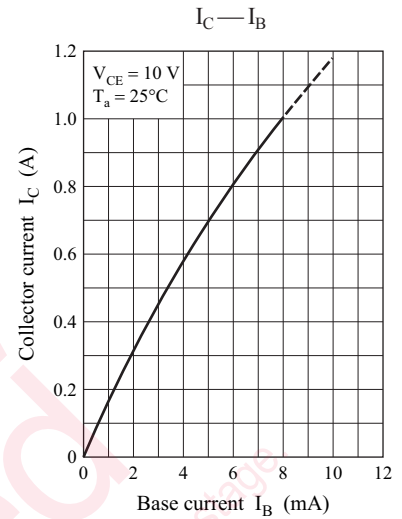
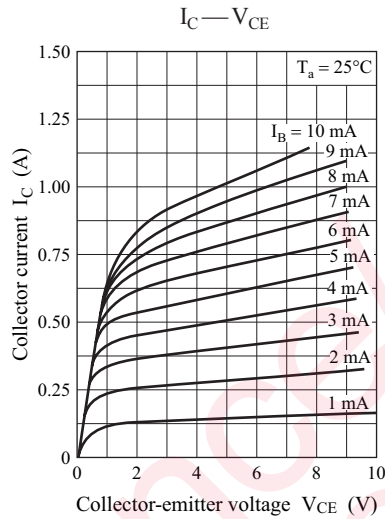
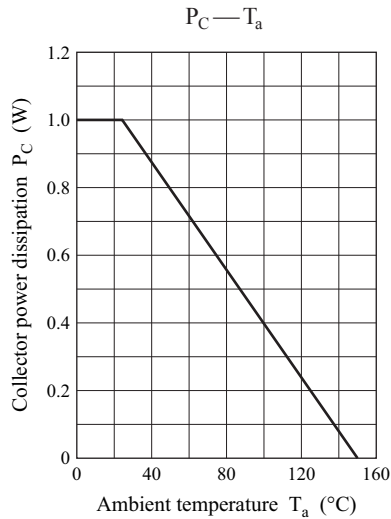
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = 10 \mu\text{A}$, $I_E = 0$	60			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 2 \text{ mA}$, $I_B = 0$	50			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 10 \mu\text{A}$, $I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 20 \text{ V}$, $I_E = 0$			0.1	μA
Forward current transfer ratio *1	h_{FE1} *2	$V_{CE} = 10 \text{ V}$, $I_C = 500 \text{ mA}$	85		340	—
	h_{FE2}	$V_{CE} = 5 \text{ V}$, $I_C = 1 \text{ A}$	50			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$		0.2	0.4	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$		0.85	1.20	V
Transition frequency	f_T	$V_{CB} = 10 \text{ V}$, $I_E = -50 \text{ mA}$, $f = 200 \text{ MHz}$		200		MHz
Collector output capacitance (Common base, input open circuited)	C_{re}	$V_{CB} = 10 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$		11	20	pF

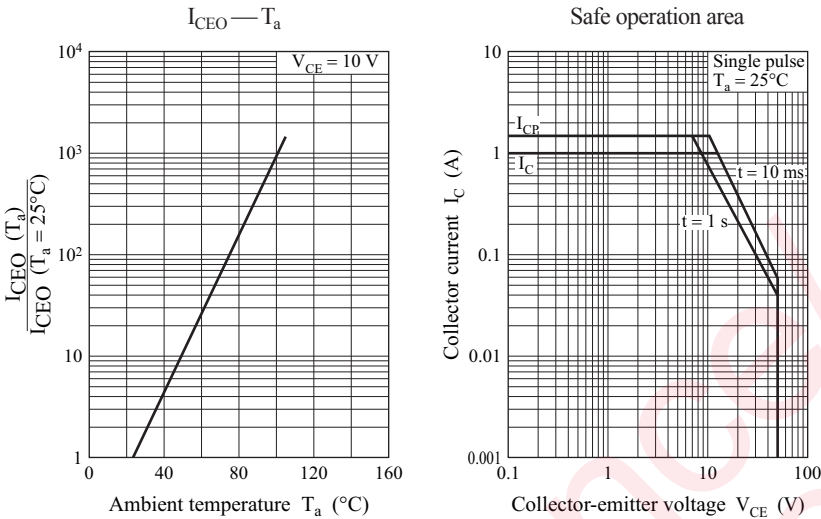
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

*2: Rank classification

Rank	Q	R	S
h_{FE1}	85 to 170	120 to 240	170 to 340



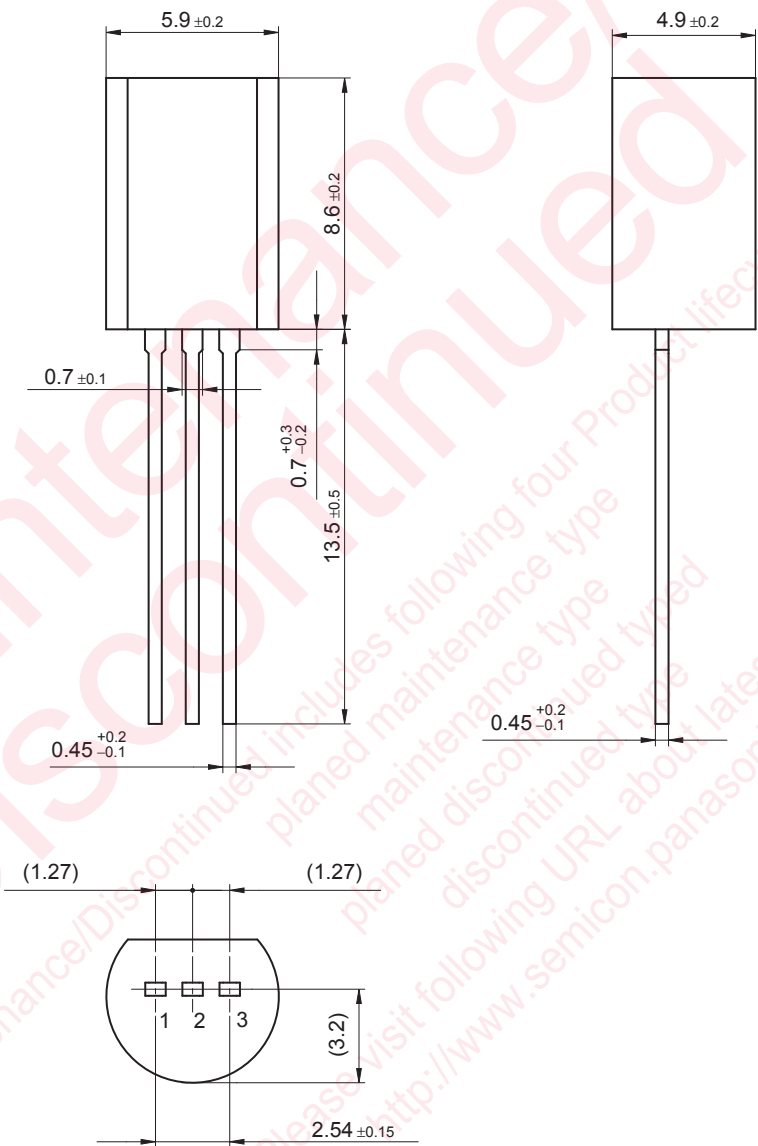


2SC1384

Panasonic

TO-92L-A1

Unit: mm



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